

# 2SC4367

Silicon NPN Epitaxial

REJ03G0724-0200  
(Previous ADE-208-1105)  
Rev.2.00  
Aug.10.2005

## Application

High Frequency amplifier

## Outline

RENESAS Package code: PRSS0003DC-A  
(Package name: TO-92 Mod)



- 1. Emitter
- 2. Collector
- 3. Base

## Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	30	V
Collector to emitter voltage	$V_{CEO}$	20	V
Emitter to base voltage	$V_{EBO}$	3	V
Collector current	$I_C$	100	mA
Collector peak current	$i_{C (peak)}$	200	mA
Collector power dissipation	$P_C$	600	mW
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

## Electrical Characteristics

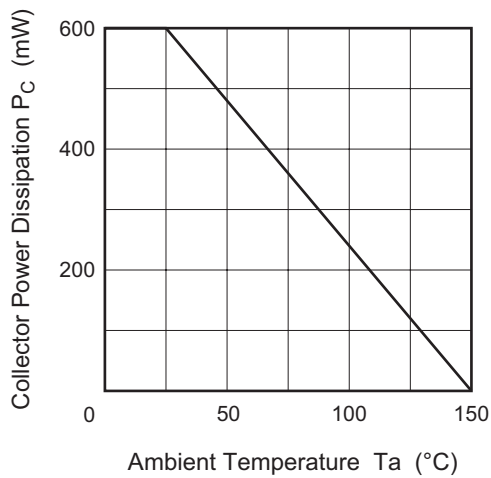
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	30	—	—	V	$I_C = 10\ \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	20	—	—	V	$I_C = 3\ mA, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	3	—	—	V	$I_E = 10\ \mu A, I_C = 0$
Collector cutoff current	$I_{CBO}$	—	—	1.0	$\mu A$	$V_{CB} = 10\ V, I_E = 0$
DC current transfer ratio	$h_{FE}$	40	—	—		$V_{CE} = 10\ V, I_C = 10\ mA$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	1.0	V	$I_C = 20\ mA, I_B = 4\ mA$
Gain bandwidth product	$f_T$	600	1000	—	MHz	$V_{CE} = 10\ V, I_C = 10\ mA$
Collector output capacitance	$C_{ob}$	—	1.3	—	pF	$V_{CB} = 10\ V, I_E = 0, f = 1\ MHz$

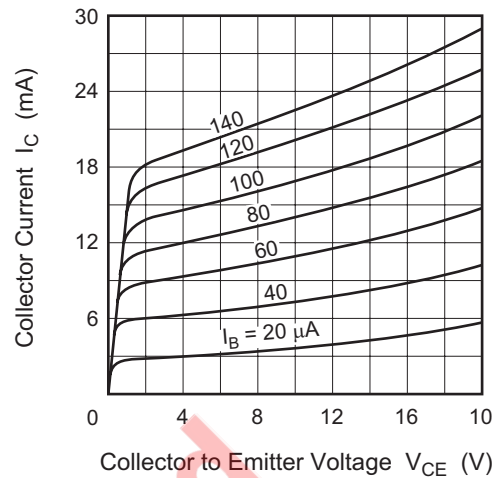
Not recommend  
for new design

## Main Characteristics

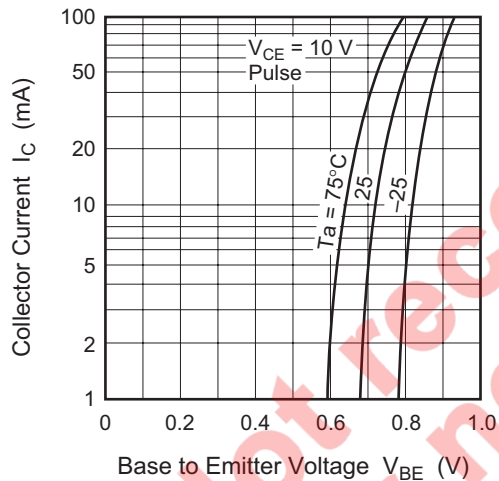
Maximum Collector Dissipation Curve



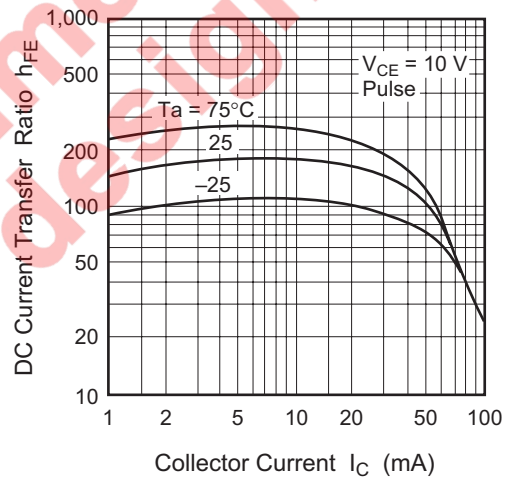
Typical Output Characteristics



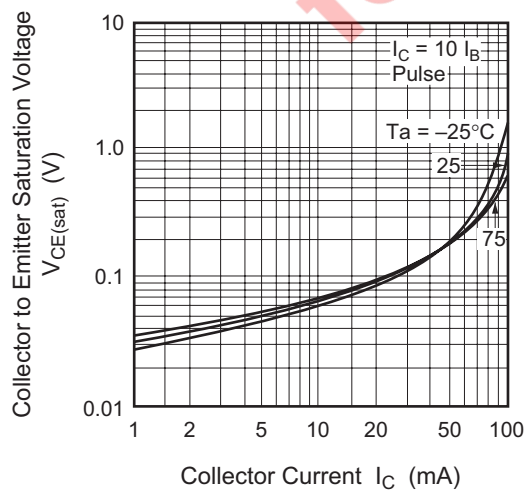
Typical Transfer Characteristics



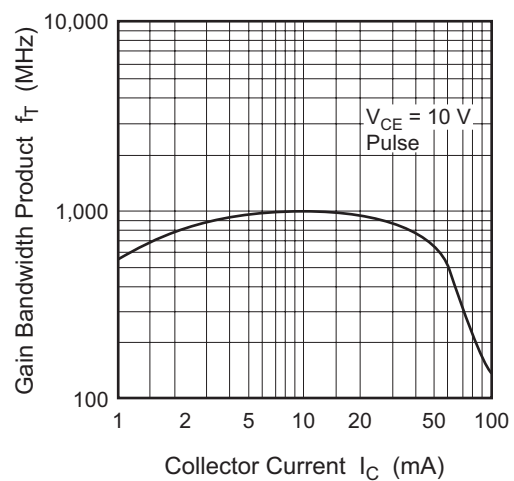
DC Current Transfer Ratio vs. Collector Current

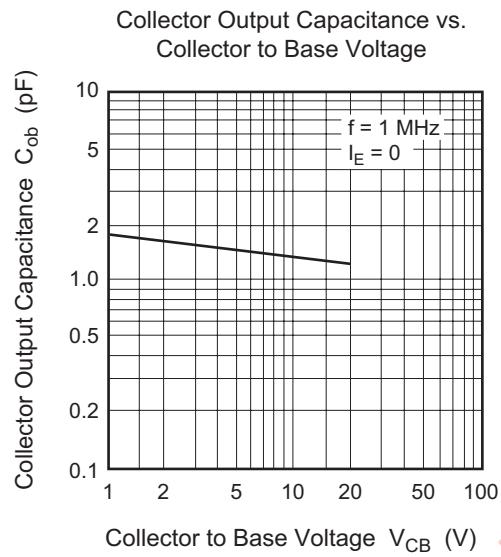


Collector to Emitter Saturation Voltage vs. Collector Current



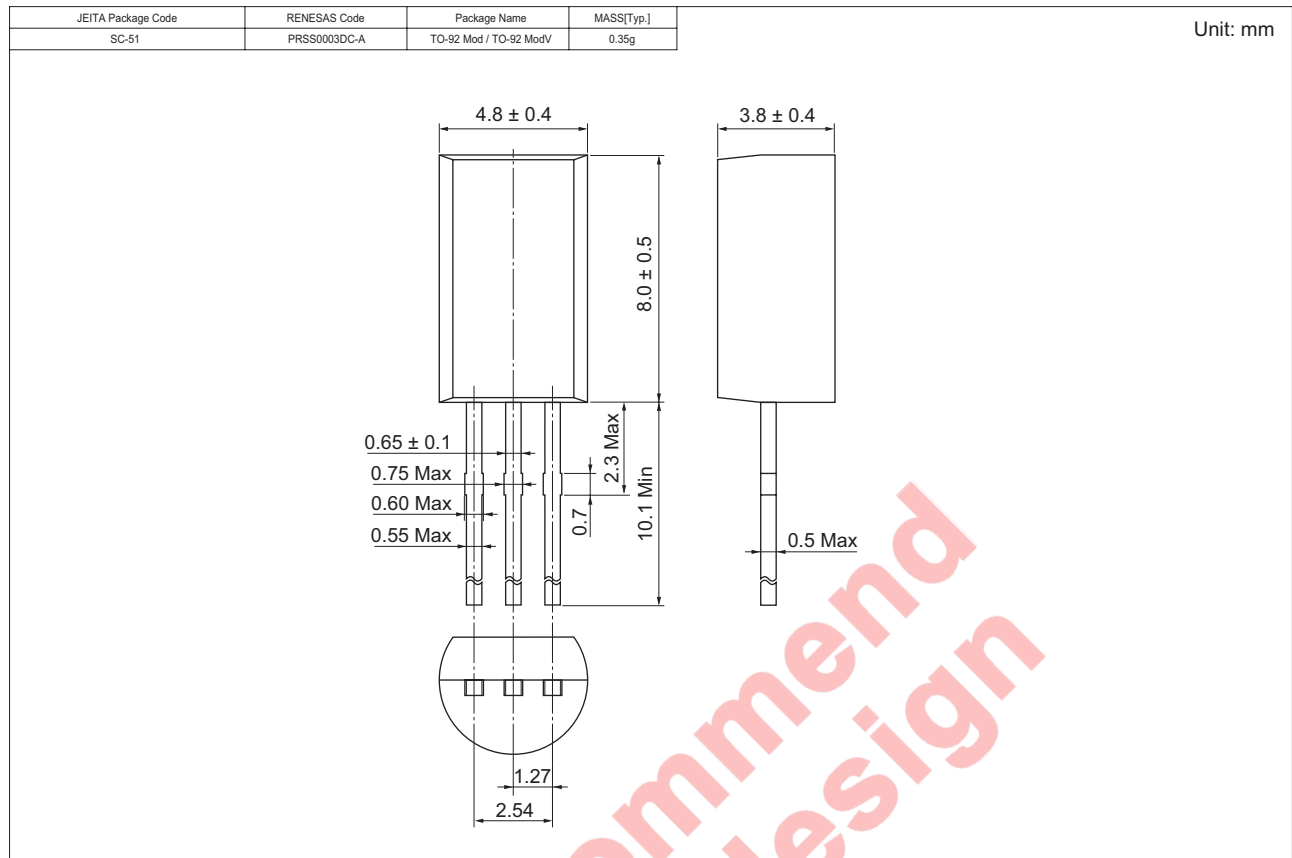
Gain Bandwidth Product vs. Collector Current





Not recommended  
for new design

## Package Dimensions



## Ordering Information

Part Name	Quantity	Shipping Container
2SC4367TZ-E	2500	Hold Box, Radial Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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